



MiniSKiiP®2

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 26NAB066V1

Features

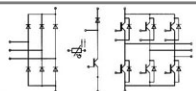
- Trench IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 12,5 kVA
- Typical motor power 5,5 kW

Remarks

- Case temperature limited to $T_C = 125^\circ\text{C}$ max.
- Product reliability results are valid for $T_s = 150^\circ\text{C}$
- SC data: $t_p \leq 6 \mu\text{s}$; $V_{GE} \leq 15 \text{ V}$; $T_J = 150^\circ\text{C}$, $V_{CC} = 360 \text{ V}$
- V_{CEsat} , V_F = chip level value



NAB

Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$, unless otherwise specified		
Symbol	Conditions	Values		Units
IGBT - Inverter, Chopper				
V_{CES}		600		V
I_C	$T_s = 25 (70)^\circ\text{C}$, $T_J = 150^\circ\text{C}$	59 (40)		A
I_C	$T_s = 25 (70)^\circ\text{C}$, $T_J = 175^\circ\text{C}$	65 (49)		A
I_{CRM}	$t_p = 1 \text{ ms}$	100		A
V_{GES}		± 20		V
Diode - Inverter, Chopper				
I_F	$T_s = 25 (70)^\circ\text{C}$, $T_J = 150^\circ\text{C}$	47 (31)		A
I_F	$T_s = 25 (70)^\circ\text{C}$, $T_J = 175^\circ\text{C}$	56 (40)		A
I_{FRM}	$t_p = 1 \text{ ms}$	100		A
Diode - Rectifier				
V_{RRM}		800		V
I_F	$T_s = 70^\circ\text{C}$	46		A
I_{FSM}	$t_p = 10 \text{ ms}$, $\sin 180^\circ$, $T_J = 25^\circ\text{C}$	370		A
i_{T1}	$t_p = 10 \text{ ms}$, $\sin 180^\circ$, $T_J = 25^\circ\text{C}$	680		A's
I_{RMS}	per power terminal (20 A / spring)	40		A
T_J	IGBT, Diode	-40...+175		$^\circ\text{C}$
T_{stg}		-40...+125		$^\circ\text{C}$
V_{Rct}	AC, 1 min.	2500		V

Characteristics		$T_s = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
$V_{CE(sat)}$	$I_{Cnom} = 50 \text{ A}$, $T_J = 25 (150)^\circ\text{C}$	1,05	1,45 (1,65)	1,85 (2,05)	V
$V_{GE(th)}$	$V_{CE} = V_{CE}$, $I_C = 1 \text{ mA}$	5,8			V
$V_{CE(TO)}$	$T_J = 25 (150)^\circ\text{C}$	0,9 (0,8)		1,1 (1)	V
r_{CE}	$T_J = 25 (150)^\circ\text{C}$	11 (17)		15 (21)	m Ω
C_{ies}	$V_{CE} = 25 \text{ V}$, $V_{GE} = 0 \text{ V}$, $f = 1 \text{ MHz}$	2,87			nF
C_{oes}	$V_{CE} = 25 \text{ V}$, $V_{GE} = 0 \text{ V}$, $f = 1 \text{ MHz}$	0,6			nF
C_{ms}	$V_{CE} = 25 \text{ V}$, $V_{GE} = 0 \text{ V}$, $f = 1 \text{ MHz}$	0,46			nF
R_{CC+EE}	spring contact-chip $T_s = 25 (150)^\circ\text{C}$				m Ω
$R_{\theta(j-a)}$	per IGBT	0,95			K/W
$t_{i(on)}$	under following conditions	25			ns
t_r	$V_{CC} = 300 \text{ V}$, $V_{GE} = -8\text{V}/+15\text{V}$	30			ns
$t_{i(off)}$	$I_{Cnom} = 50 \text{ A}$, $T_J = 150^\circ\text{C}$	285			ns
t_f	$R_{con} = R_{coff} = 12 \Omega$	55			ns
$E_{on} (E_{off})$	inductive load	1,6 (1,6)			mJ
Diode - Inverter, Chopper					
$V_F = V_{EC}$	$I_F = 50 \text{ A}$, $T_J = 25 (150)^\circ\text{C}$	1,5 (1,5)		1,7 (1,7)	V
$V_{(TO)}$	$T_J = 25 (150)^\circ\text{C}$	1 (0,9)		1,1 (1)	V
r_T	$T_J = 25 (150)^\circ\text{C}$	10 (12)		12 (14)	m Ω
$R_{\theta(j-a)}$	per diode	1,6			K/W
I_{RRM}	under following conditions	59			A
O_{rr}	$I_{Fnom} = 50 \text{ A}$, $V_R = 300 \text{ V}$	5,9			μC
E_{rr}	$V_{GE} = 0 \text{ V}$, $T_J = 150^\circ\text{C}$	1,3			mJ
	$di_F/dt = 2100 \text{ A}/\mu\text{s}$				
Diode - Rectifier					
V_F	$I_{Fnom} = 25 \text{ A}$, $T_J = 25^\circ\text{C}$	1,1			V
$V_{(TO)}$	$T_J = 150^\circ\text{C}$	0,8			V
	$T_J = 150^\circ\text{C}$	13			m Ω
$R_{\theta(j-a)}$	per diode	1,5			K/W
Temperature Sensor					
R_{ts}	3 %, $T_s = 25 (100)^\circ\text{C}$	1000(1670)			Ω
Mechanical Data					
w		65		9	g
M_b	Mounting torque	2		2,5	Nm

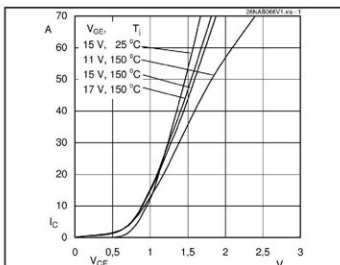


Fig. 1 Typ. output characteristics

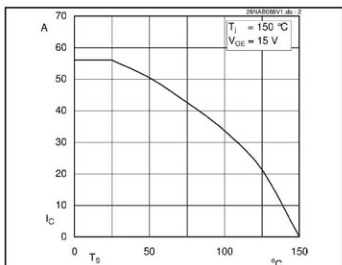


Fig. 2 Typ. rated current vs. temperature

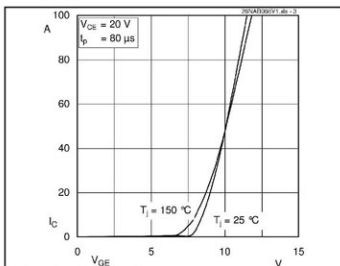


Fig. 3 Typ. transfer characteristic

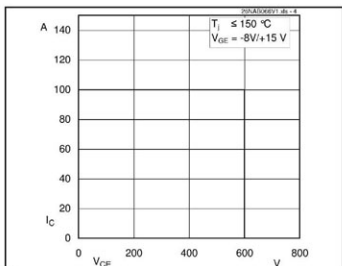


Fig. 4 Reverse bias safe operating area

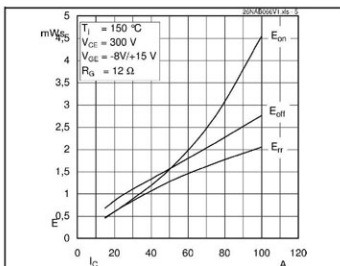


Fig. 5 Turn-on/off energy = $f(I_C)$

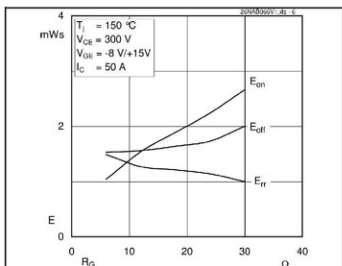


Fig. 6 Turn-on/off energy = $f(R_G)$

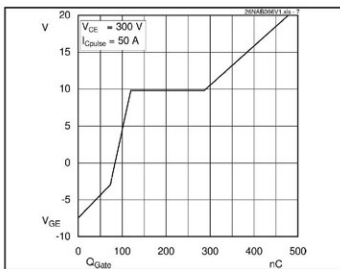


Fig. 7 Typ. gate charge

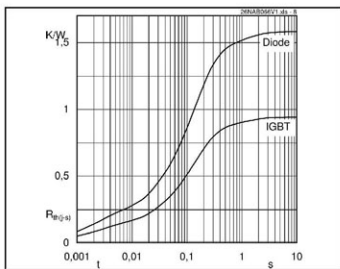


Fig. 8 Typ. thermal impedance

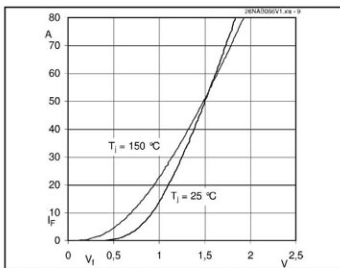


Fig. 9 Typ. freewheeling diode forward characteristic

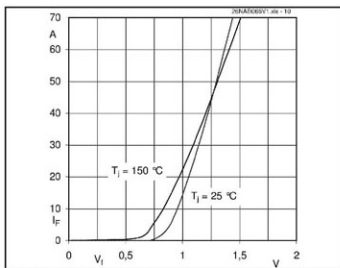


Fig. 10 Typ. input bridge forward characteristic

